NCL30073LED1GEVB

15 W High Power Factor LED Driver Evaluation Board User's Manual

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EVAL BOARD USER'S MANUAL

Overview

This manual covers the specification, theory of operation, testing and construction of the NCL30073LED1GEVB evaluation board. The NCL30073 board demonstrates a 15 W high PF flyback LED driver for a typical downlight application.

Key Features

The key features of this evaluation board include:

- Low Parts Count
- TRIAC Dimmer compatible
- High Power Factor
- Integrated Fault Protection
  - Over Temperature on board (a PCB mounted PTC)
  - Output Over Current
  - Output Over Voltage

Table 1. SPECIFICATIONS

Input voltage	108 – 132 V ac	
Line Frequency	60 Hz	
Power Factor (100% Load)	0.9	Min
Output Voltage	36 V dc	
Output Ripple	13%	Pk – Pk
Output Current	415 mA dc	± 5%
Efficiency	85.7%	Typ.
Start Up Time	< 100 msec	Typ.

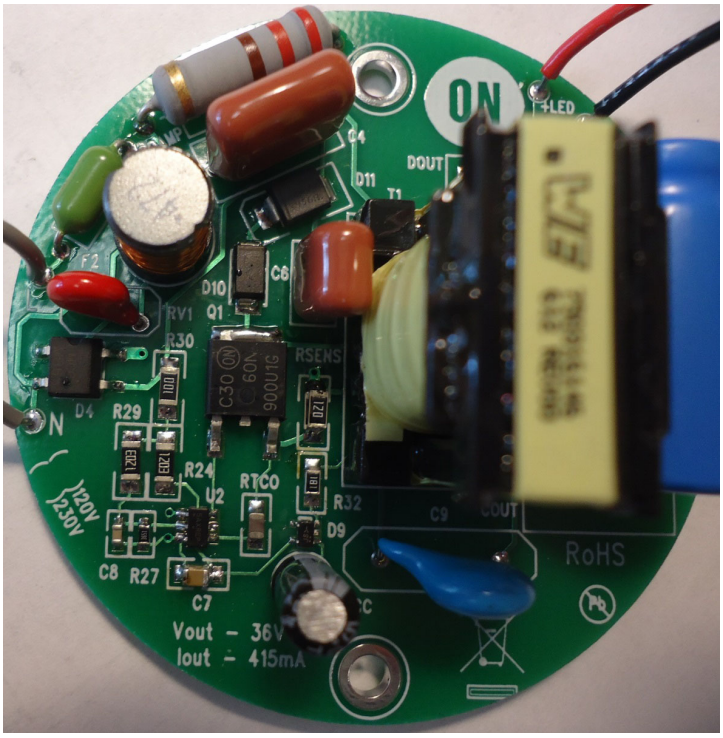


Figure 1. Evaluation Board Photo

THEORY OF OPERATION

Power Stage

The power stage is a flyback design. The power stage operates as a fixed frequency DCM power stage. The DCM allows for no forced commutation of the output diode for good EMI performance. The fixed current/fixed frequency provides for a constant power control over a large portion of the input waveform. The resistor divider of R27 and R29 provides some wave shaping to improve the power factor. The input current waveform is made to be square for maximum TRIAC dimmer compatibility.

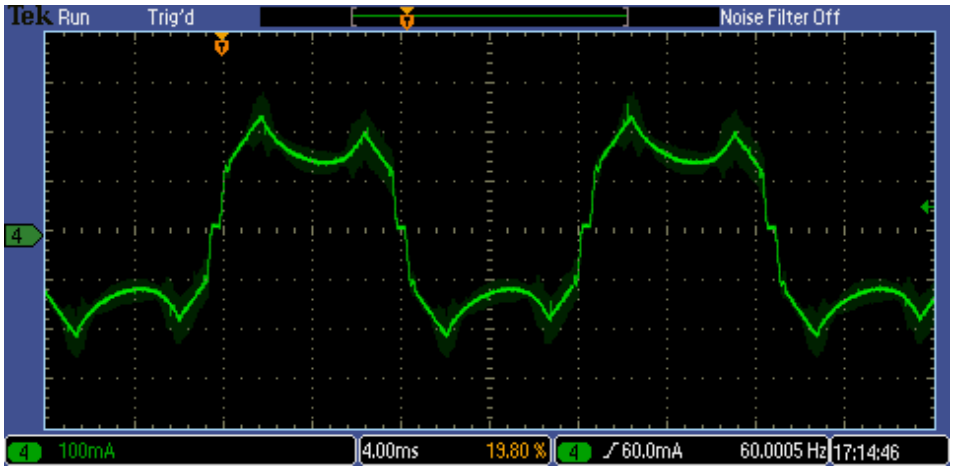


Figure 2.

Output Voltage Sense and Vcc generation

D9 is rectifies the voltage on the aux winding and stores energy in Cvcc. Cvcc is diode isolated from U2 Vcc to allow for fast start up. C7 will charge much faster than Cvcc and allow for fast starting.

In cases where the output has a lot of ripple current and the LED has high dynamic resistance, the peak output voltage can be much higher than the average output voltage. The inductor winding will charge the Cvcc to the peak of the output voltage which may trigger the OVP sooner than expected so in this case the peak voltage of the LED string is critical.

Protection

Thermal Protection

Rtco is a PTC connected between the CS pin and Rsens. The controller creates and internal signal current from the CS pin. As the resistance of Rtco becomes larger with temperature, the signal level at the CS pin increases causing the current to foldback with temperature.

Programmable OVP

The OVP threshold is 25 V on the Vcc pin of U2. This is set by the turns ratio of the flyback transformer. A transformer change is necessary to adjust the OVP threshold. R32 helps to filter the leakage inductance spike to avoid false OVP.

Overcurrent Protection

The controller has built in overcurrent limits.

Output Current

The output current is set by the value of Rsens. It's possible to adjust the output current by changing Rsens.

TRIAC Dimming Compatibility

The EMI filter components are selected to provide optimum damping of the EMI filter to eliminate ringback of the input current which will lead to loss of hold current in the dimmer. The square nature of the input current makes the best case for TRIAC holding current over the line cycle while still maintaining power factor above 0.9.

SCHEMATIC

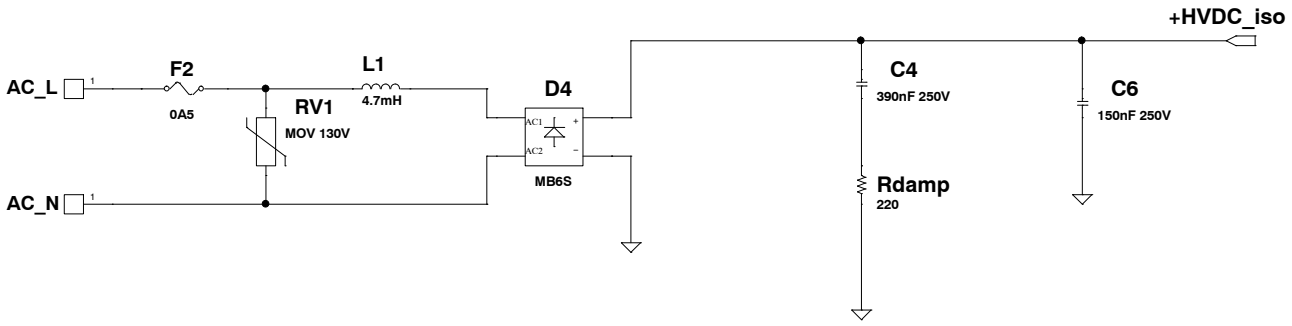


Figure 3. Input Circuit

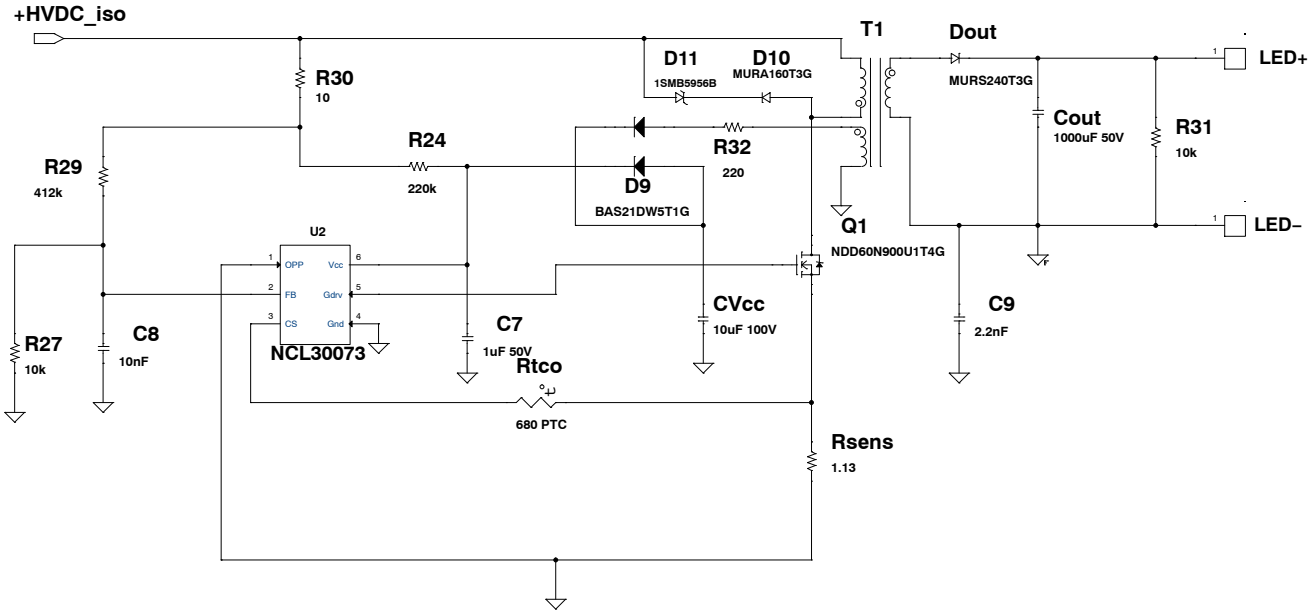


Figure 4. Main Circuit

BILL OF MATERIAL

Table 2. BILL OF MATERIAL

Refer-ence	Qty	Part	Distributor	Distributor Part Number	Manufacturer	Manufacturer Part Number	Substitution Allowed
CVcc	1	10 μF 100 V	Rubycon	100YXJ10M5X11	Digikey	1189−2150−ND	Yes
Cout	1	1000 μF 50 V	Vishay	MAL214251102E3	Digikey	4603PHBK−ND	Yes
C4	1	390 nF 250 V	Faratronic	C252E394−40****+++	Faratronic	C252E394−40****+++	Yes
C6	1	150 nF 250 V	Faratronic	C252E154−20****+++	Faratronic	C252E154−20****+++	Yes
C7	1	1 μF 50 V	Yageo	CC0805KKX7R9BB105	Digikey	311−1886−1−ND	Yes
C8	1	10 nF	Yageo	CC0603KRX7R9BB103	Digikey	311−1085−1−ND	Yes
C9	1	2.2 nF	Murate	DE1E3KX222MN4AL01	Digikey	490−7889−1−ND	Yes
Dout	1	MURS240T3G	ON Semiconductor	MURS240T3G	ON Semiconductor	MURS240T3G	No
D4	1	MB6S	MCC	MB6S	Digikey	MB6S−TPMSCT−ND	Yes
D9	1	BAS21DW5T1G	ON Semiconductor	BAS21DW5T1G	ON Semiconductor	BAS21DW5T1G	No
D10	1	MURA160T3G	ON Semiconductor	MURA160T3G	ON Semiconductor	MURA160T3G	No
D11	1	1SMB5956B	ON Semiconductor	MMSZ18T1	ON Semiconductor	1SMB5956B	No
F2	1	0A5	Littelfuse	0263.500WRT1L	Digikey	F1999CT−ND	Yes
L1	1	4.7 mH	Wurth	744772472	Digikey	732−3790−ND	Yes
Q1	1	NDD60N900U1T4G	ON Semiconductor	NDD60N900U1T4G	ON Semiconductor	NDD60N900U1T4G	No
RV1	1	MOV 130V	Littelfuse	V220ZA05P	Digikey	F3049−ND	Yes
Rdamp	1	220	Yageo	RSF200JB−73−220R	Digikey	220W−2−ND	Yes
Rsens	1	1.13	Yageo	RC1206FR−071R13L	Digikey	311−1.13FRCT−ND	Yes
Rtco	1	680 PTC	Epcos	B59721A90A62	Digikey	495−4312−1−ND	Yes
R24	1	220k	Yageo	RC1206FR−07220KL	Digikey	311−220KFRCT−ND	Yes
R27	1	10k	Yageo	RC0603FR−0710k0L	Digikey	311−10.0KHRCT−ND	Yes
R29	1	412k	Yageo	RC1206FR−07412KL	Digikey	311−412KFRCT−ND	Yes
R30	1	10	Yageo	RC1206FR−0710RL	Digikey	311−10.0FRCT−ND	Yes
R31	1	10k	Yageo	RC1206FR−0710KL	Digikey	311−10.0KFRTR−ND	Yes
R32	1	220	Yageo	RC0805FR−07220RL	Digikey	311−220CRCT−ND	Yes
T1	1	XFRM_LINEAR	Wurth	750316146	Wurth	750316146	Yes
U2	1	NCL30073	ON Semiconductor	NCL30073	ON Semiconductor	NCL30073	No

NOTE: All components to comply with RoHS 2002/95/EC

GERBER VIEWS

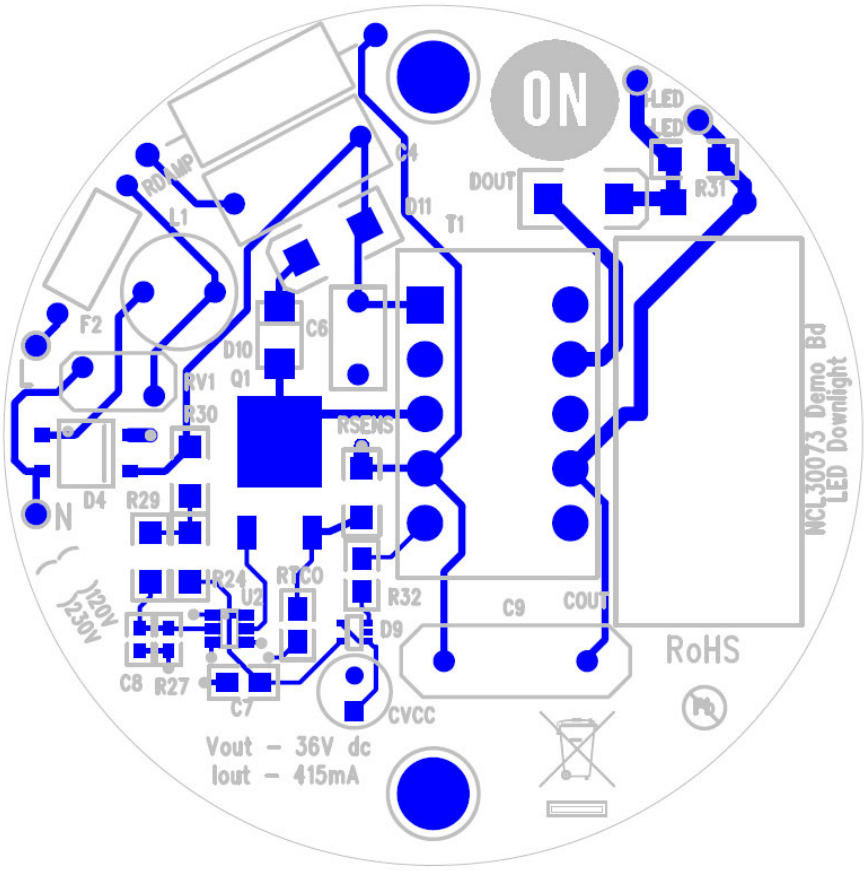


Figure 5. Top Side PCB

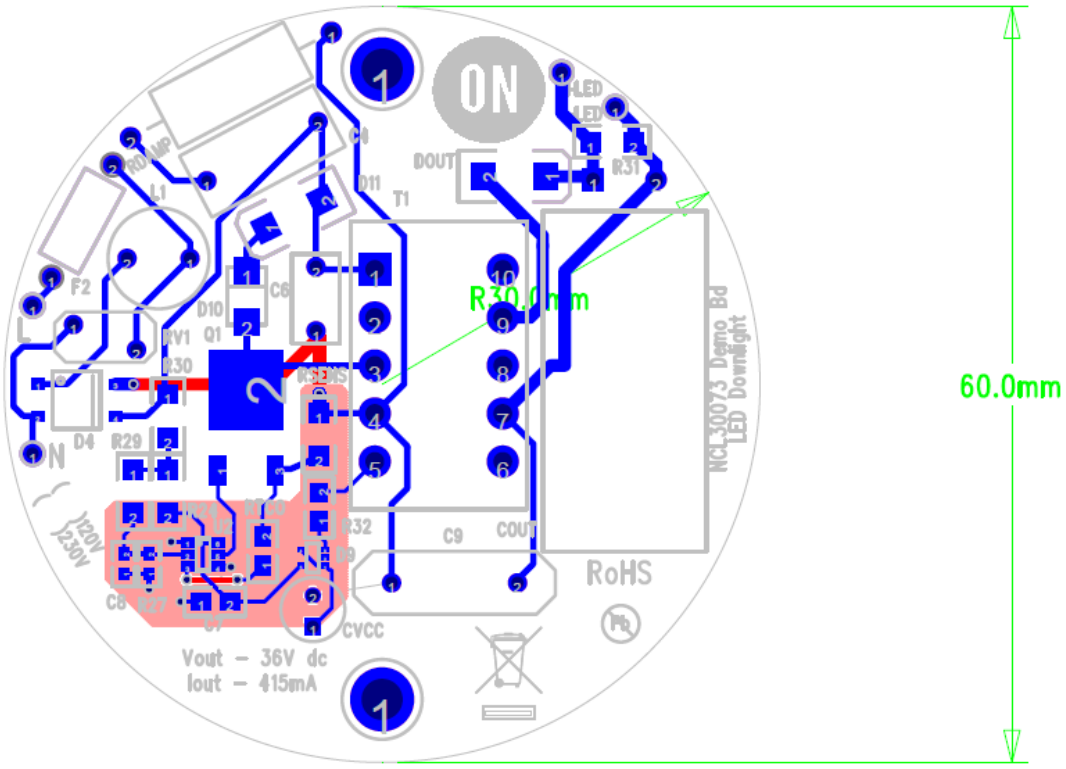


Figure 6. PCB Outline

Circuit Board Fabrication Notes

1. Fabricate per IPC−6011 and IPC6012. Inspect to IPA−A−600 Class 2 or updated standard.
2. Printed Circuit Board is defined by files listed in fileset.
3. Modification to copper within the PCB outline is not allowed without permission, except where noted otherwise. The manufacturer may make adjustments to compensate for manufacturing process, but the final PCB is required to reflect the associated gerber file design ± 0.001 in. for etched features within the PCB outline.
4. Material in accordance with IPC−4101/21, FR4, Tg 125°C min.
5. Layer to layer registration shall not exceed ± 0.004 in.
6. External finished copper conductor thickness shall be 0.0026 in. min. (ie 2oz)
7. Copper plating thickness for through holes shall be 0.0013 in. min. (ie 1oz)
8. All holes sizes are finished hole size.
9. Finished PCB thickness 0.062 in.
10. All un-dimensioned holes to be drilled using the NC drill data.
11. Size tolerance of plated holes: ± 0.003 in. : non−plated holes ± 0.002 in.
12. All holes shall be ± 0.003 in. of their true position U.D.S.
13. Construction to be SMOBC, using liquid photo image (LPI) solder mask in accordance with IPC−SM−B40C, Type B, Class 2, and be green in color.
14. Solder mask mis-registration ± 0.004 in. max.
15. Silkscreen shall be permanent non−conductive white ink.
16. The fabrication process shall be UL approved and the PCB shall have a flammability rating of UL94V0 to be marked on the solder side in silkscreen with date, manufactures approved logo, and type designation.
17. Warp and twist of the PCB shall not exceed 0.0075 in. per in.
18. 100% electrical verification required.
19. Surface finish: electroless nickel immersion gold (ENIG)
20. RoHS 2002/95/EC compliance required.

ECA PICTURES

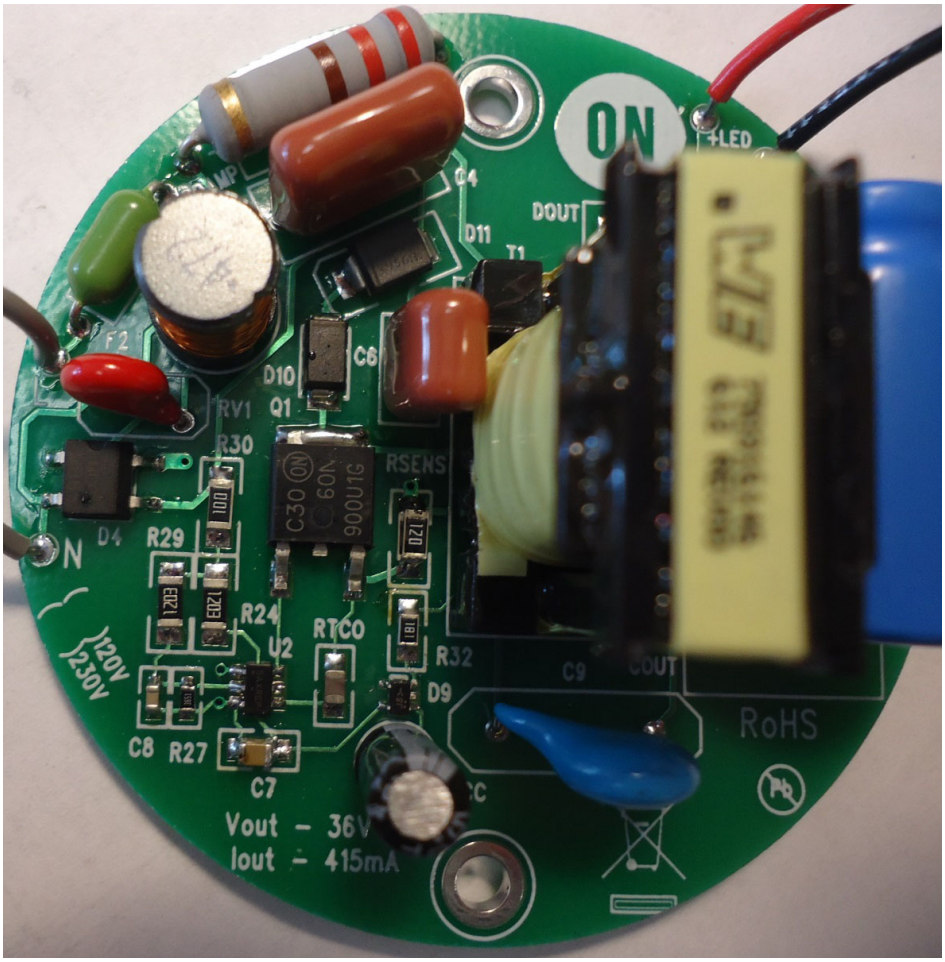


Figure 7. Top View

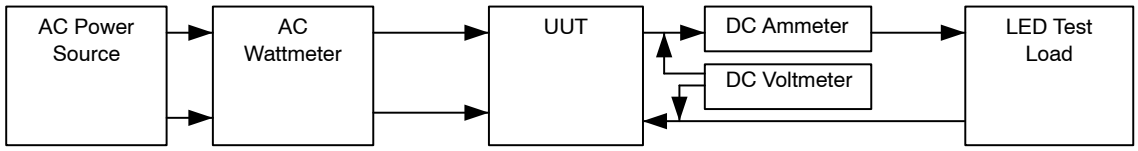
TEST PROCEDURE

Equipment Needed

- AC Source – 90 to 140 V ac 60 Hz Minimum 100 W capability
- AC Wattmeter – 100 W Minimum, True RMS Input Voltage, Current, Power Factor, and THD 0.2% accuracy or better
- DC Voltmeter – 300 V dc minimum 0.1% accuracy or better
- DC Ammeter – 1 A dc minimum 0.1% accuracy or better
- LED Load – 30 V – 36 V @ 415 mA

Test Connections

1. Connect the LED Load to the red(+) and black(−) leads through the ammeter shown in Figure 10. **Caution: Observe the correct polarity or the load may be damaged.**
2. Connect the AC power to the input of the AC wattmeter shown in Figure 8. Connect the white leads to the output of the AC wattmeter
3. Connect the DC voltmeter as shown in Figure 8.



Note: Unless otherwise specified, all voltage measurements are taken at the terminals of the UUT.

Figure 8. Test Set Up

Functional Test Procedure

1. Set the LED Load for 36V output.
2. Set the input power to 120 V 60 Hz.
   Caution: Do not touch the ECA once it is energized because there are hazardous voltages present.

Regulation

120 V / Max Load

Table 3.

	Output Current	Output Power	Power Factor	THD
108 V				
120 V				
132 V				

$$\text{Efficiency} = \frac{\text{Vout} \times \text{Iout}}{\text{Pin}} \times 100\%$$

TEST DATA

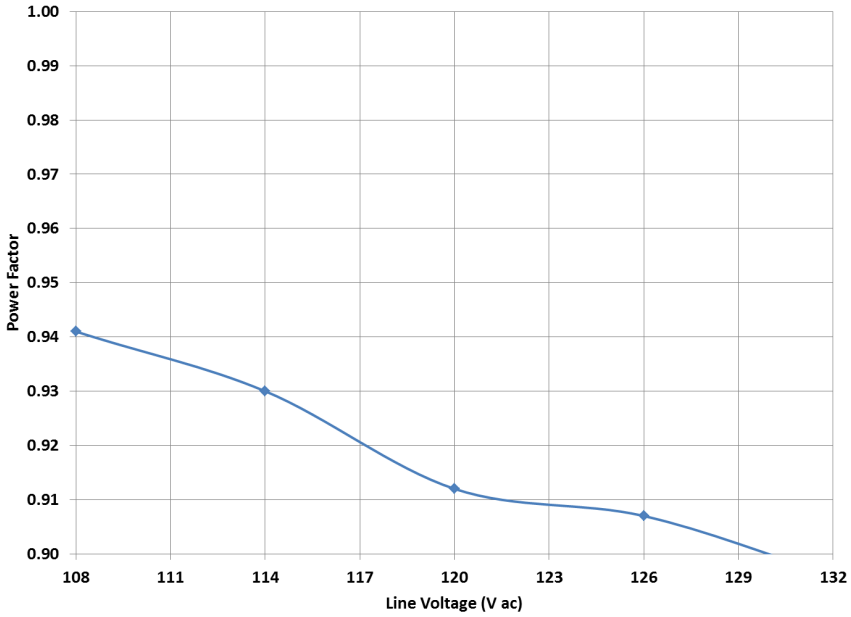


Figure 9. Power Factor Over Line

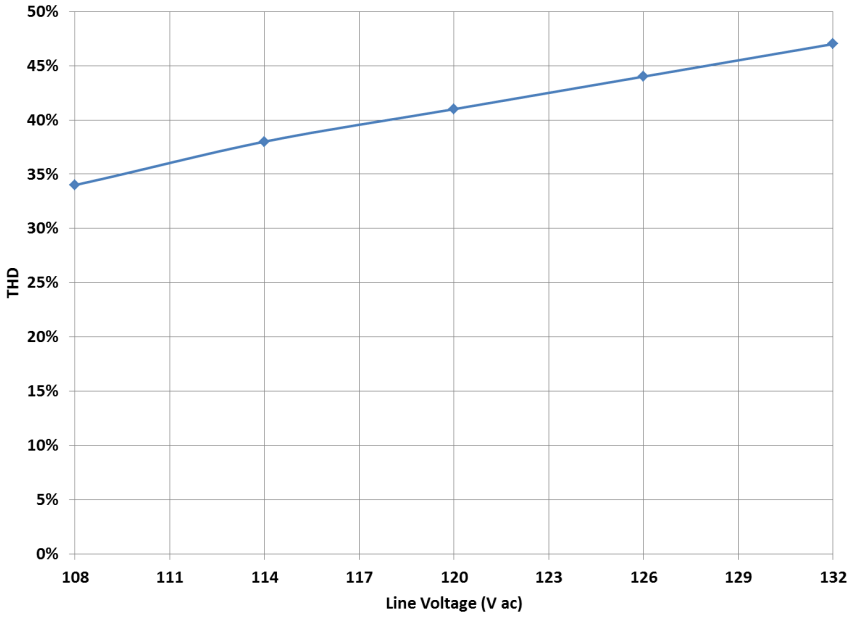


Figure 10. THD Over Line

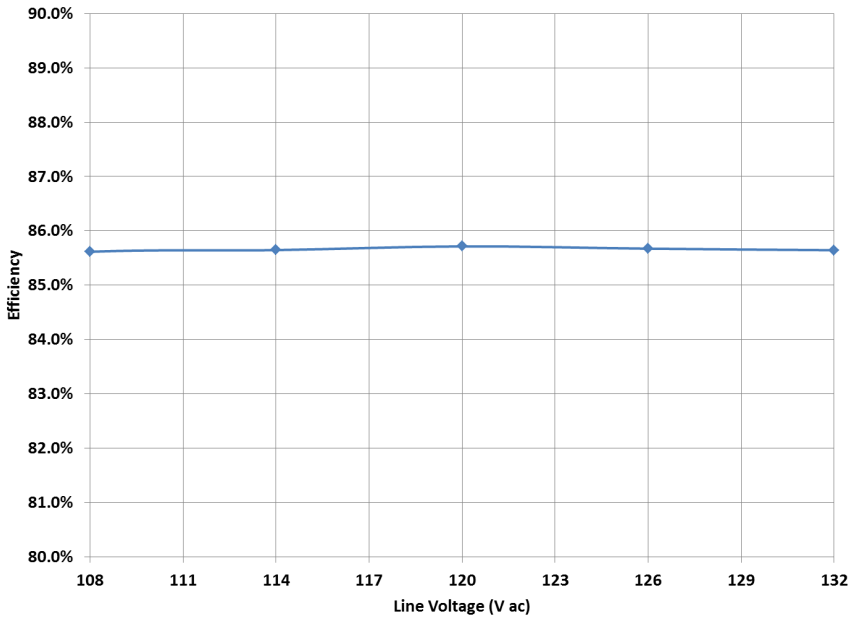


Figure 11. Efficiency

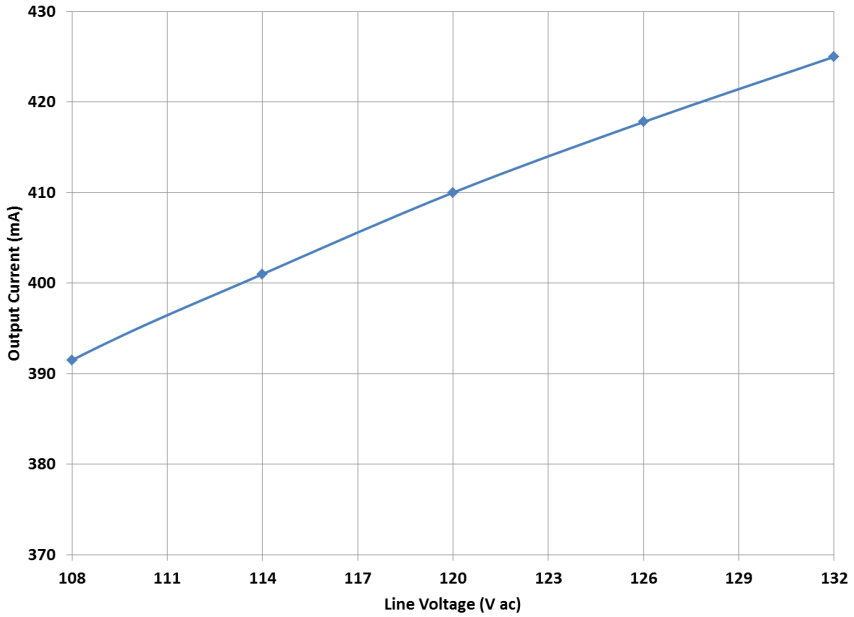


Figure 12. Regulation Over Line

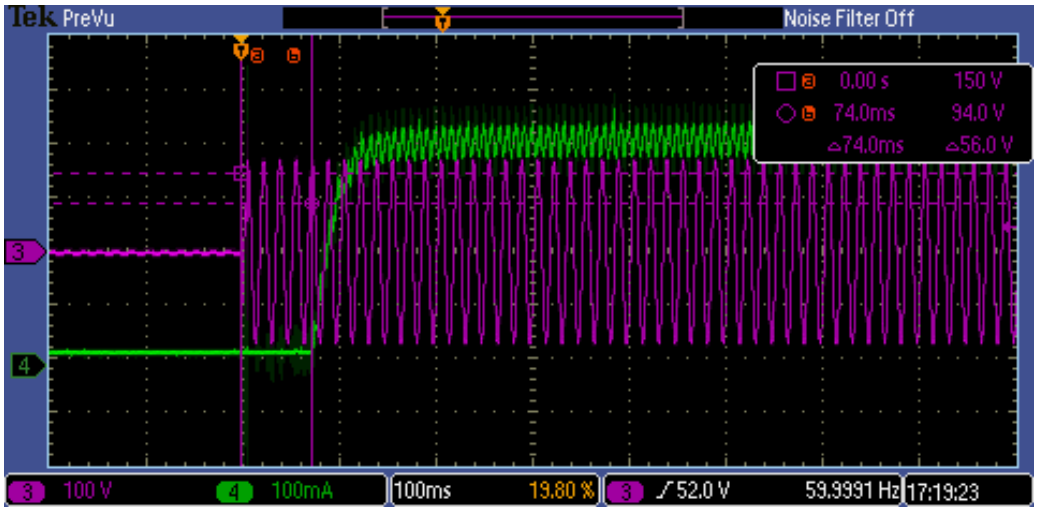


Figure 13. Start Up with AC Applied 120 V

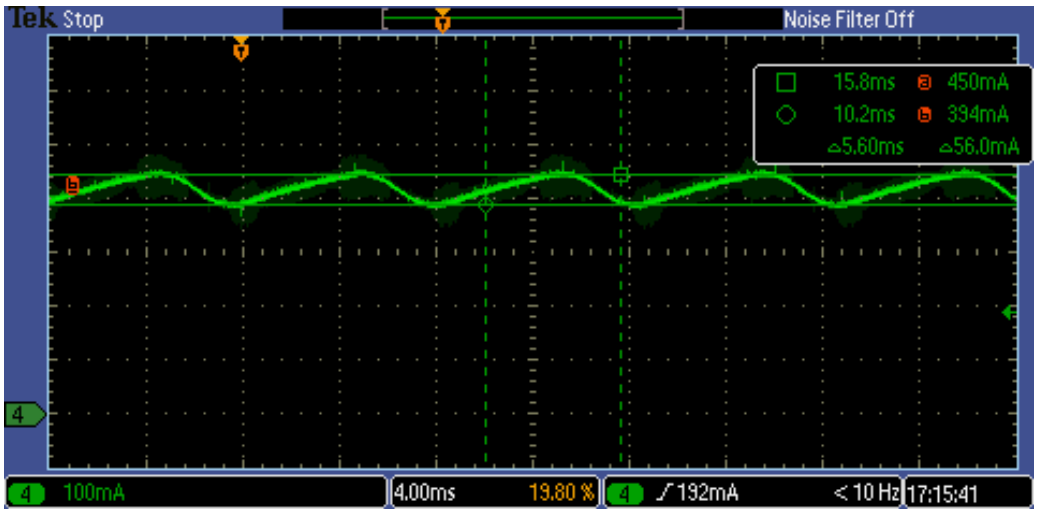


Figure 14. Output Ripple 13% Pk − Pk

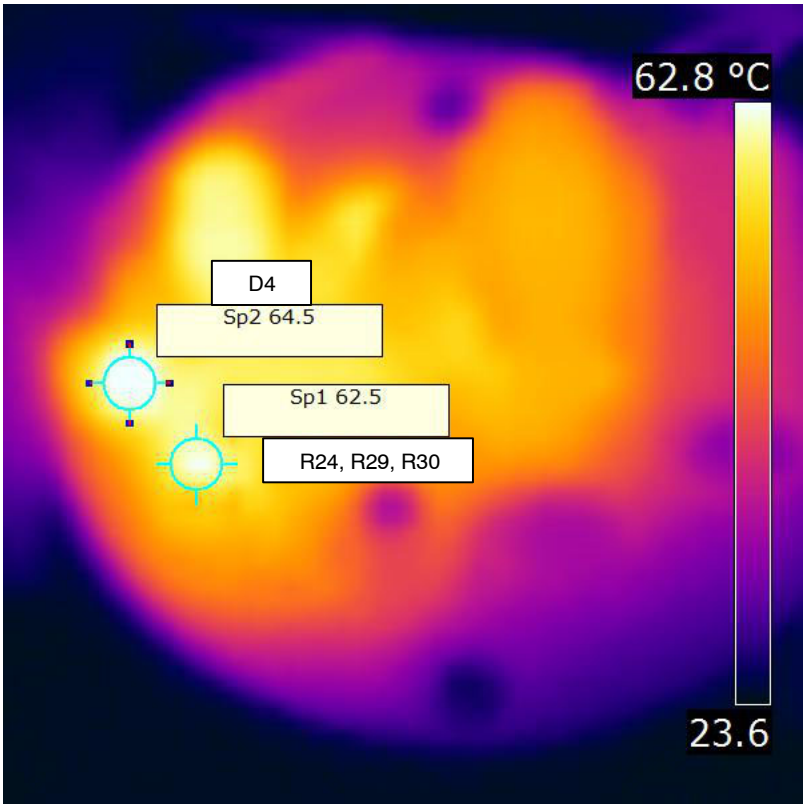


Figure 15.

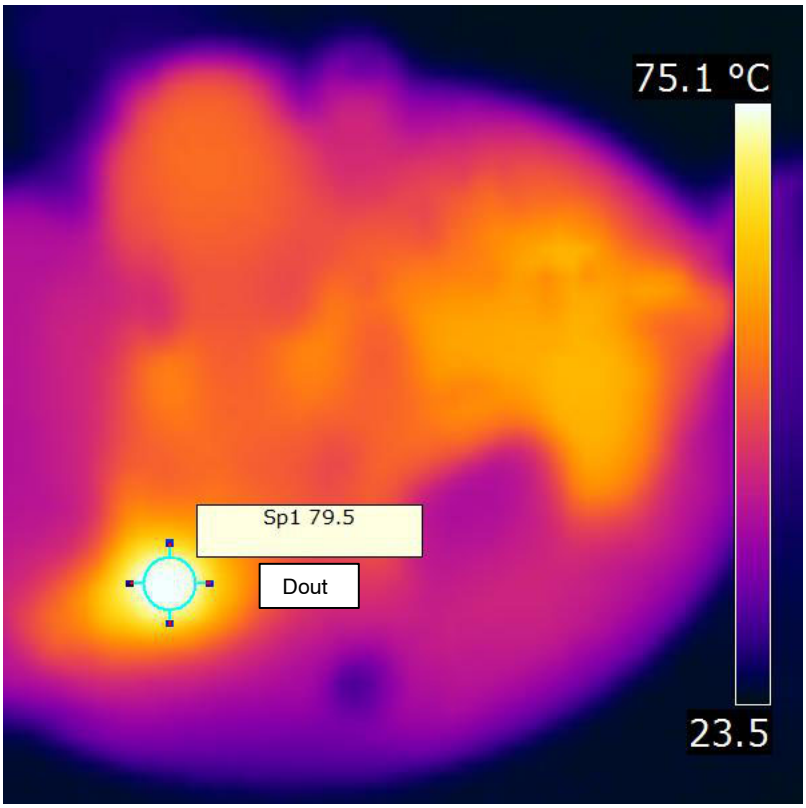


Figure 16. Thermal Image SMT Side

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